



## 100V P-Channel Enhancement Mode MOSFET

Voltage

-100 V

Current

-2.6 A

#### **Features**

- $R_{DS(ON)}$ ,  $V_{GS}@-10V$ , $I_D@-2.6A<210m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@-4.5V$ , $I_D@-1A<230m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: SOT-223 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.043 ounces, 0.123grams

Marking: W3P10A

# SOT-223 Drain Gate Source

## **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	-100	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current	T <sub>A</sub> =25°C	- I <sub>D</sub>	-2.6		
	T <sub>A</sub> =70°C		-2.0	А	
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	-10.4	А	
Power Dissipation	T <sub>A</sub> =25°C		3.1	W	
	T <sub>A</sub> =70°C	P <sub>D</sub>	2		
Operating Junction and Storage Temperature Range		$T_{J}$ , $T_{STG}$	-55~150	°C	
Typical Thermal resistance		_			
- Junction to Ambient (Note 5)		$R_{\theta JA}$	40.3	°C/W	

Limited only By Maximum Junction Temperature





# Electrical Characteristics (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =-250uA	-100	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250uA$	-1.0	-1.9	-3.0	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V,I <sub>D</sub> =-2.6A	-	170	210	mΩ
		V <sub>GS</sub> =-4.5V,I <sub>D</sub> =-1A	-	190	230	
Zero Gate Voltage Drain Current	$I_{DSS}$	V <sub>DS</sub> =-100V,V <sub>GS</sub> =0V	-	-	-1.0	uA
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	Qg	V <sub>DS</sub> =-80V, I <sub>D</sub> =-2.6A, V <sub>GS</sub> =-10V <sup>(Note 1,2)</sup>	-	20	-	nC
Gate-Source Charge	$Q_gs$		-	3.5	-	
Gate-Drain Charge	$Q_{gd}$		-	4.6	-	
Input Capacitance	Ciss	251/11/201/	-	1419	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =-25V, V <sub>GS</sub> =0V, f=1.0MHZ	-	89	-	
Reverse Transfer Capacitance	Crss	I=I.UIVIMZ	-	45	-	
Turn-On Delay Time	td <sub>(on)</sub>	\/ 50\/ ID 0.04	-	18	-	ns
Turn-On Rise Time	t <sub>r</sub>	$V_{DS}$ =-50V,ID=-2.6A, $V_{GS}$ =-10V, $R_{G}$ =25 $\Omega$ (Note 1,2)	-	8	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	100	-	
Turn-Off Fall Time	t <sub>f</sub>		-	30	-	
Drain-Source Diode						
Maximum Continuous Drain-Source				-	-2.6	A
Diode Forward Current	I <sub>S</sub>		-			
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =-1A,V <sub>GS</sub> =0V	-	-0.75	-1.2	V

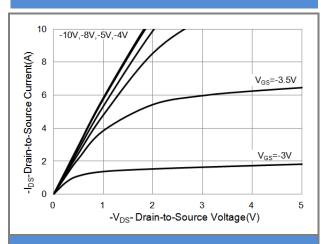
#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 5. Rejua is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**



**Fig.1 Output Characteristics** 

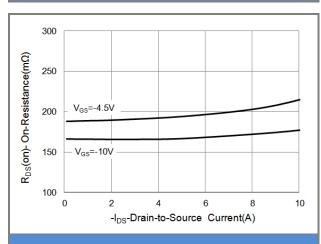
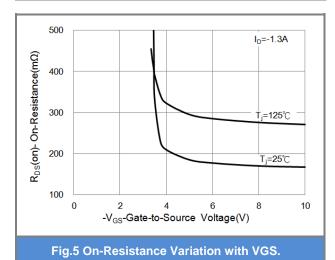


Fig.3 On-Resistance vs. Drain Current



10 V<sub>DS</sub>=-5V V

8 V<sub>DS</sub>=-5V T<sub>J</sub>=125°C T<sub>J</sub>=25°C T<sub>J</sub>=25

Fig.2 Transfer Characteristics

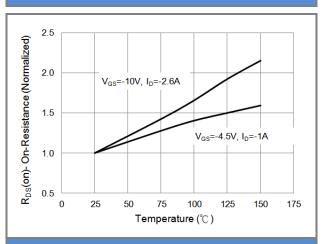


Fig.4 On-Resistance vs. Junction temperature

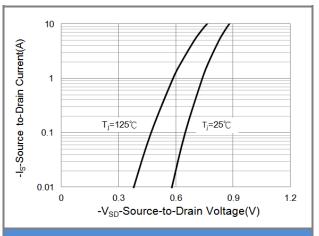


Fig.6 Source-Drain Diode Forward Voltage





#### **TYPICAL CHARACTERISTIC CURVES**

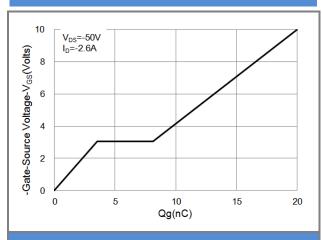


Fig.7 Gate-Charge Characteristics

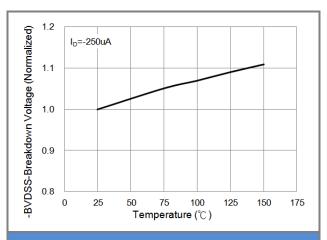


Fig.8 Breakdown Voltage Variation vs. Temperature

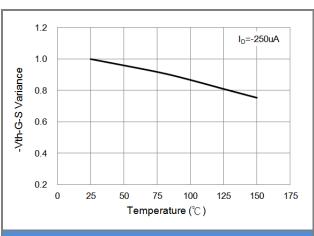


Fig.9 Threshold Voltage Variation with Temperature

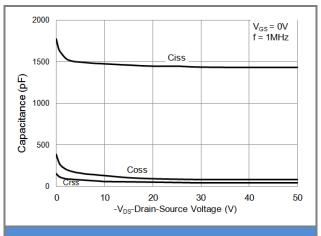
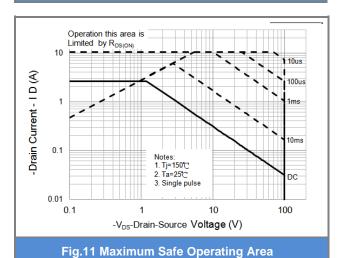


Fig.10 Capacitance vs. Drain-Source Voltage







#### **TYPICAL CHARACTERISTIC CURVES**

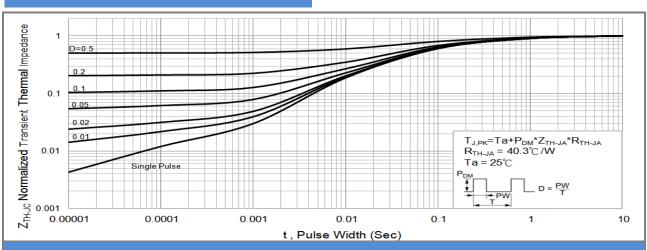
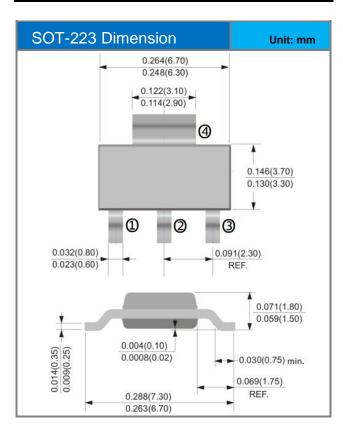


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width





## **Packaging Information**



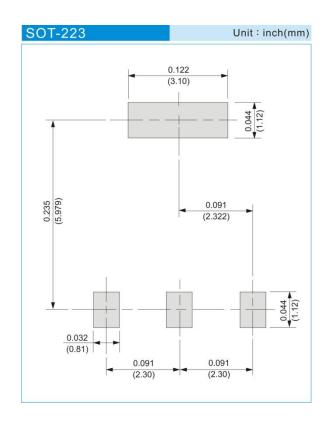




## PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Packing Type Marking	
PJW3P10A_R2_00001	SOT-223	2,500pcs / 13" reel	W3P10A	Halogen free

## **MOUNTING PAD LAYOUT**







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